

GaAs IC High Isolation Positive Control SPDT Switch DC–3.0 GHz



AS177-86

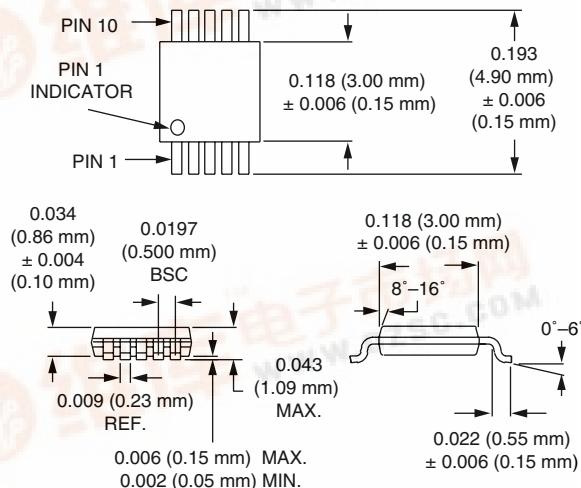
Features

- Positive Voltage Control (0/+3, +5 V)
- High Isolation (50 dB @ 0.9, 1.9 GHz)
- Low DC Power Consumption
- Ideal for GSM, PCS, 3G and ISM 2.4 GHz Applications
- Miniature Low Cost MSOP-10 Plastic Package

Description

The AS177-86 is a GaAs FET IC SPDT switch packaged in a MSOP-10 plastic package for low cost, high isolation commercial applications. Ideal building block for base station dual band applications where synthesizer isolation is critical. Use in conjunction with the AS165-59 SPST switch to meet GSM synthesizer isolation requirements.

MSOP-10



Electrical Specifications at 25°C (0, +3 V), (0, +5 V)

Parameter ¹	Condition	Frequency ²	Min.	Typ.	Max.	Unit
Insertion Loss ³		DC–1.0 GHz 1.0–2.0 GHz 2.0–3.0 GHz		0.7 0.8 0.9	0.85 1.00 1.20	dB dB dB
Isolation	J ₁ –J ₂ /J ₁ –J ₃ J ₁ –J ₂ /J ₁ –J ₃	DC–2.0 GHz 2.0–2.5 GHz 2.5–3.0 GHz	44/50 41/44 34	48/55 46/50 40		dB dB
VSWR ⁴		DC–3.0 GHz		1.3:1	1.5:1	

Operating Characteristics at 25°C (0, +5 V)

Parameter	Condition	Frequency	Min.	Typ.	Max.	Unit
Switching Characteristics ⁵	Rise, Fall (10/90% or 90/10% RF) On, Off (50% CTL to 90/10% RF) Video Feedthru			50 100 25		ns ns mV
Input Power for 1 dB Compression	+3 V +5 V	0.5–3.0 GHz 0.5–3.0 GHz		+21 +27		dB dB
Intermodulation Intercept Point (IP3)	Two-tone Input Power +5 dBm +3 V +5 V	0.5–3.0 GHz 0.5–3.0 GHz		+41 +45		dBm dBm
Control Voltages	V _{Low} = 0 to 0.2 V @ 20 μA Max. V _{High} = +3 V @ 100 μA Max. to +5 V @ 200 μA Max. V _S = V _{High} ± 0.2 V					

1. All measurements made in a 50 Ω system, unless otherwise specified.

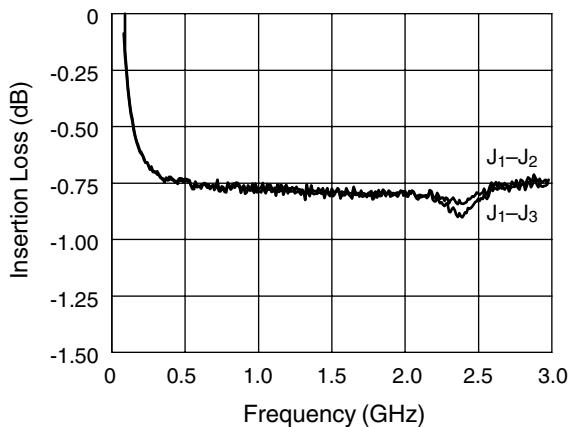
2. DC = 300 kHz.

3. Insertion loss changes by 0.003 dB/°C.

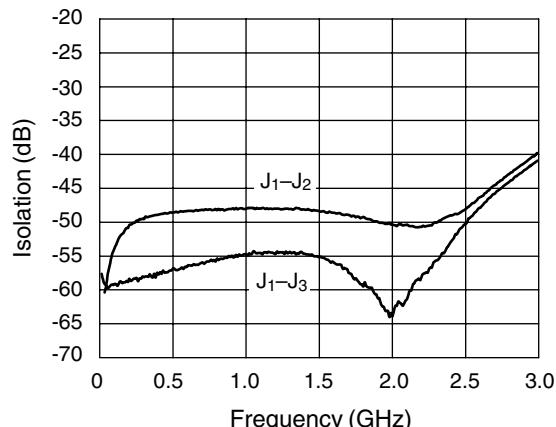
4. Insertion loss state.

5. Video feedthru measured with 1 ns risetime pulse and 500 MHz bandwidth.

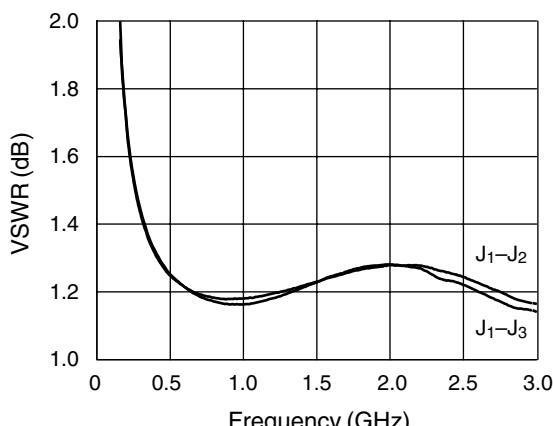
Typical Performance Data (0, +5 V)



Insertion Loss vs. Frequency



Isolation vs. Frequency



VSWR vs. Frequency

Truth Table

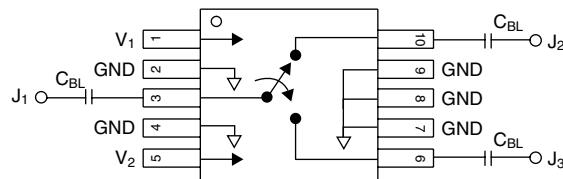
V ₁	V ₂	J ₁ -J ₂	J ₁ -J ₃
0	V _{High}	Isolation	Insertion Loss
V _{High}	0	Insertion Loss	Isolation

V_{High} = +3 V to +5 V.

Absolute Maximum Ratings

Characteristic	Value
RF Input Power	1 W Max. > 500 MHz 0/+8 V Control
Supply Voltage	+8 V
Control Voltage	-0.2 V, +8 V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C
θ _{JC}	25°C/W

Pin Out



C_{BL} = 47 pF for operation >500MHz.